

# SOD-523 Plastic-Encapsulate Diodes

## BAT54X Schottky Barrier Diode

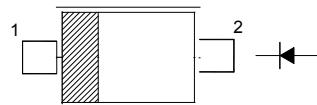
### FEATURES

- Extremely Fast Switching Speed
- Low Forward Voltage

**MARKING: JV**

### PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Top View

Simplified outline SOD-523 and symbol

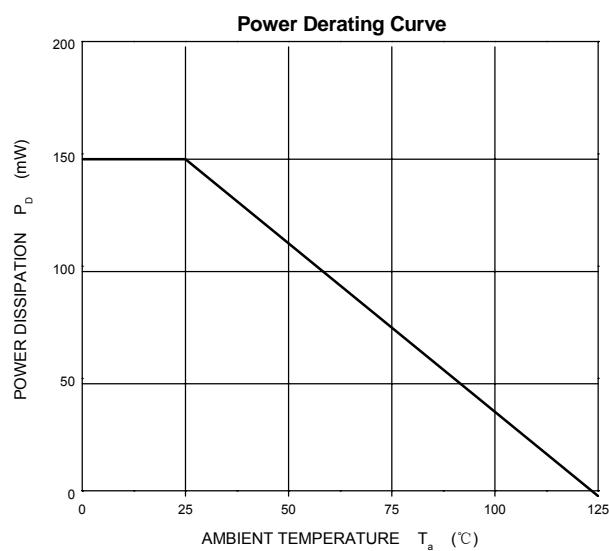
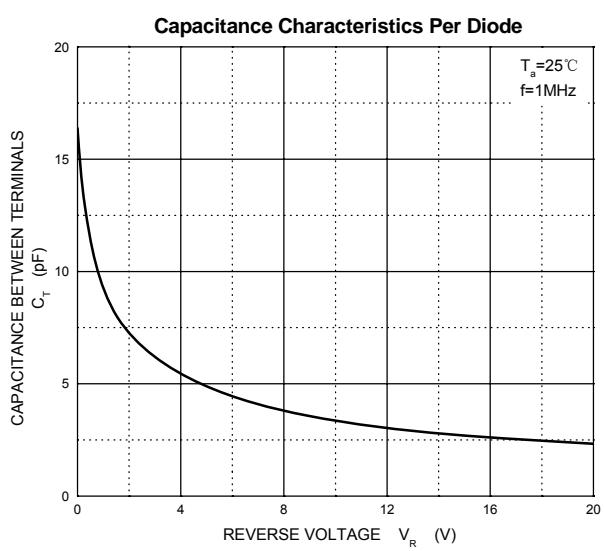
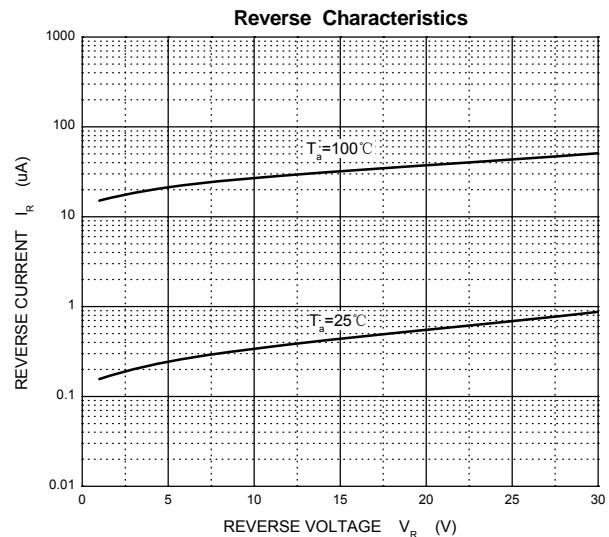
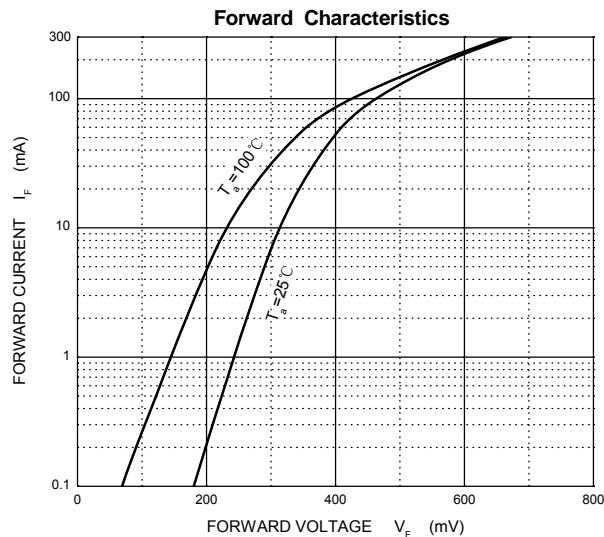
### Maximum Ratings @Ta=25°C

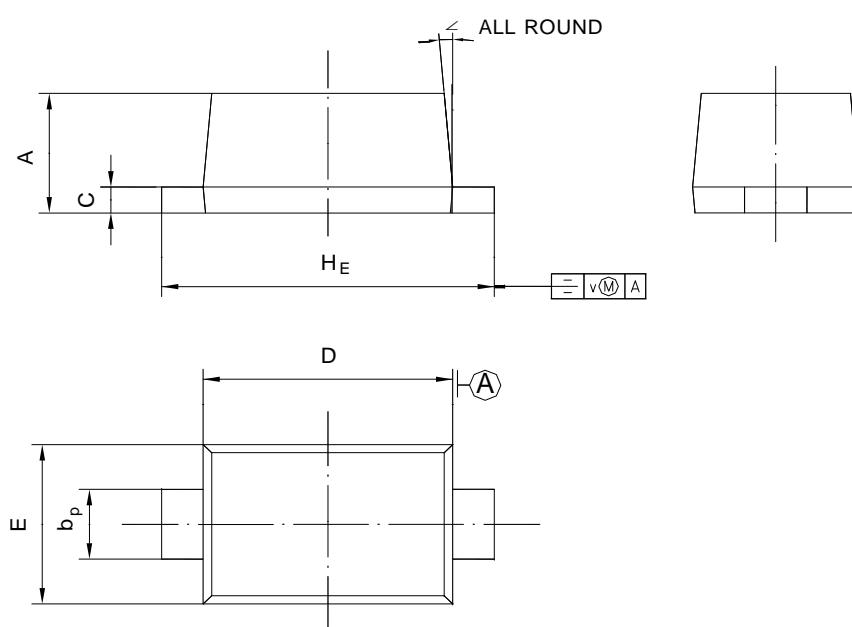
Parameter	Symbol	Limit	Unit
Non-repetitive peak reverse voltage	V <sub>RM</sub>	30	V
DC blocking voltage	V <sub>R</sub>	21	V
Average rectified output current	I <sub>O</sub>	100	mA
Forward continuous current	I <sub>F</sub>	200	mA
Repetitive peak forward current	I <sub>FRM</sub>	300	mA
Peak Forward Surge Current (t= 10 ms)	I <sub>FSM</sub>	600	mA
Power dissipation	P <sub>d</sub>	150	mW
Thermal resistance junction to ambient	R <sub>θJA</sub>	667	°C/W
Junction temperature	T <sub>J</sub>	125	°C
Storage temperature range	T <sub>STG</sub>	-55~+150	°C

### Electrical Characteristics @Ta=25°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse breakdown voltage	V <sub>(BR)</sub>	I <sub>R</sub> =100μA	30			V
Forward voltage	V <sub>F1</sub>	I <sub>F</sub> =0.1mA			240	mV
	V <sub>F2</sub>	I <sub>F</sub> =1.0mA			320	mV
	V <sub>F3</sub>	I <sub>F</sub> =10mA			400	mV
	V <sub>F4</sub>	I <sub>F</sub> =30mA			500	mV
	V <sub>F5</sub>	I <sub>F</sub> =100mA			1000	mV
Reverse current	I <sub>R</sub>	V <sub>R</sub> =25V			2.0	uA
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> =10mA, I <sub>R</sub> =10mA to 1mA , R <sub>L</sub> =100Ω			5.0	ns
Capacitance between terminals	C <sub>T</sub>	V <sub>R</sub> =1V,f=1MHz			10	pF

## Typical Characteristics



**PACKAGE OUTLINE****SOD-523****Plastic surface mounted package; 2 leads**

UNIT	A	b <sub>p</sub>	C	D	E	H <sub>E</sub>	V	∠
mm	0.70 0.60	0.4 0.3	0.135 0.100	1.25 1.15	0.85 0.75	1.7 1.5	0.1	5°